

## Innovating Energy Technology

# **FMW79N60S1HF**

http://www.fujielectric.com/products/semiconductor/ **FUJI POWER MOSFET** 

## **Super SJ MOS series**

### N-Channel enhancement mode power MOSFET

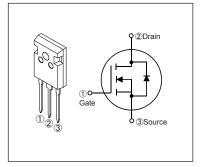
Features

Pb-free lead terminal RoHS compliant

Applications

For switching

### Equivalent circuit schematic



### ■ Absolute Maximum Ratings at T<sub>c</sub>=25°C (unless otherwise specified)

Parameter	Symbol	Characteristics	Unit	Remarks
Drain Source Voltage	V <sub>DS</sub>	600	V	
Drain-Source Voltage	V <sub>DSX</sub>	600	V	V <sub>GS</sub> =-30V
Continuous Brain Current		DD #68	А	Tc=25°C Note*1
Continuous Drain Current	lo ~ RST	1 K/2 = 43 [ ] ] ]	А	Tc=100°C Note*1
Pulsed Drain Current	lop/	±204	A	Note *1
Gate-Source Voltage	VGS POTO	5\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	V	
Repetitive and Non-Repetitive Maximum Avalanche Current	TAR	1135ct	А	Note *2
Non-Repetitive Maximum Avalanche Energy	Thice PI	3194.4	す。 mJ	Note *3
Maximum Drain-Source dV/dt	dVos/dt _= t	5願し、50	kV/ns	V <sub>DS</sub> ≤ 600V
Peak Diode Recovery dV/dt	dylatta	ianin915	kV/ns	Note *4
Peak Diode Recovery -di/dt	-di/dt new at	50	A/µs	Note *5
Maximum Bower Dissipation 女妇設計(これ)	in tor	2.5	W	T <sub>a</sub> =25°C
waxiiiuiii rowei bissipatioii (注: 新加 not use	FD	545	VV	Tc=25°C
Maximum Power Dissipation  (注:新規設計となると  Operating and Storage Temperature Pange	Tch	150	°C	
Operating and Storage remperature range	T <sub>stg</sub>	-55 to +150	°C	

Note \*1 : Limited by maximum channel temperature.

Note \*2 : T<sub>ch≤150°</sub>C, See Fig.1 and Fig.2

Note \*3 : Starting T<sub>ch=25°C</sub>, I<sub>As=8.1</sub>A, L=89.3mH, V<sub>DD=60</sub>V, R<sub>o=50Ω</sub>, See Fig.1 and Fig.2

E<sub>As</sub> limited by maximum channel temperature and avalanche current.

Note \*4 : I<sub>F≤-20A</sub>, -di/dt=50A/µs, V<sub>DD≤</sub> 300V, V<sub>DS Peak≤</sub> 600V, T<sub>ch≤150°C</sub>.

Note \*5 : IF  $\leq$  -20A, dV/dt = 15kV/ $\mu$ s, VDD  $\leq$  300V, VDS peak  $\leq$  600V, Tch  $\leq$  150°C.

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# ■ Electrical Characteristics at T<sub>c</sub>=25°C (unless otherwise specified) • Static Ratings

Parameter	Symbol	Conditions		min.	typ.	max.	Unit
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	I <sub>D</sub> =250μA V <sub>GS</sub> =0V		600	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	I <sub>D</sub> =250µA V <sub>DS</sub> =V <sub>GS</sub>		2.5	3.0	3.5	V
Zero Gate Voltage Drain Current	loss	V <sub>DS</sub> =600V V <sub>GS</sub> =0V	T <sub>ch</sub> =25°C	-	-	25	μА
		V <sub>DS</sub> =480V V <sub>GS</sub> =0V	T <sub>ch</sub> =125°C	-	-	250	
Gate-Source Leakage Current	Igss	V <sub>GS</sub> = ± 30V V <sub>DS</sub> =0V	·	-	10	100	nA
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	I <sub>D</sub> =34A V <sub>GS</sub> =10V		-	0.034	0.04	Ω
Gate resistance	R <sub>G</sub>	f=1MHz, open drain		-	1.3	_	Ω

### Dynamic Ratings

Parameter	Symbol	Conditions	min.	typ.	max.	Unit
Forward Transconductance	gfs	I <sub>D</sub> =34A V <sub>DS</sub> =25V	27.5	55	-	S
Input Capacitance	Ciss	V <sub>DS</sub> =10V	13/3	7000	-	
Output Capacitance	Coss	V <sub>GS</sub> =0V	35/4	14500	-	
Reverse Transfer Capacitance	Crss	f=1MHz	ST PLE	1300	-	
Effective output capacitance, energy related (Note *6)	C <sub>o(er)</sub>	V <sub>cs</sub> =0V V <sub>os</sub> =0, (480V		350	-	pF
Effective output capacitance, time related (Note *7)	Cola	Ves=0/Ves=0.1480V Ves=0.1480V Ves=10V Ves=400V, Ves=10V Ves=480V, Ves=10V Ves=480V, Ves=10V Ves=10V See Fig.5	Juict	1330	-	
Turn-On Time	tdon)	- to the state of	1,0,1,50	40 /	-	
Turn-Oil Time	to Man	V6=100V, V6=10V	ind.	107	-	ns
Turn-Off Time	t <sub>d(off)</sub>	See Fig.3 and Fig.4	-	199	-	113
Turn-On Time	t <sub>f</sub>	Eticitizen for new	-	20	-	
Total Gate Charge	Qo新規節	est use them	-	203	-	
Gate-Source Charge	Paga. DO	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	-	44	-	nC
Gate-Drain Charge	Q <sub>GS</sub> DO	See Fig.5	-	76	-	IIC
Drain-Source crossover Charge	Qsw		-	27	-	

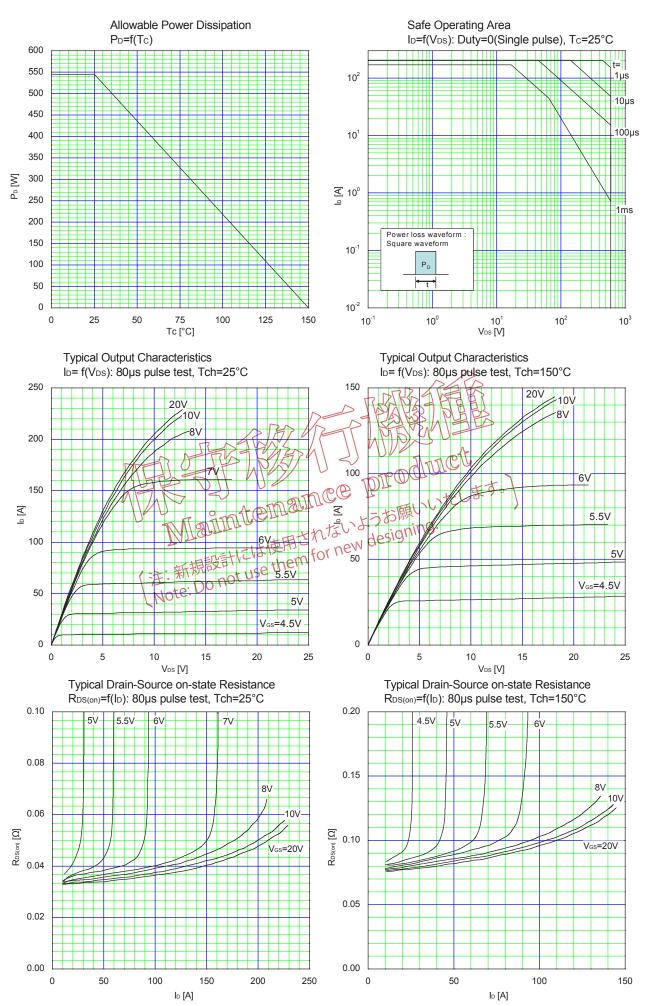
Note \*6 : Co(er) is a fixed capacitance that gives the same stored energy as Coss while Vos is rising from 0 to 80% BVoss. Note \*7 : Co(tr) is a fixed capacitance that gives the same charging times as Coss while Vos is rising from 0 to 80% BVoss.

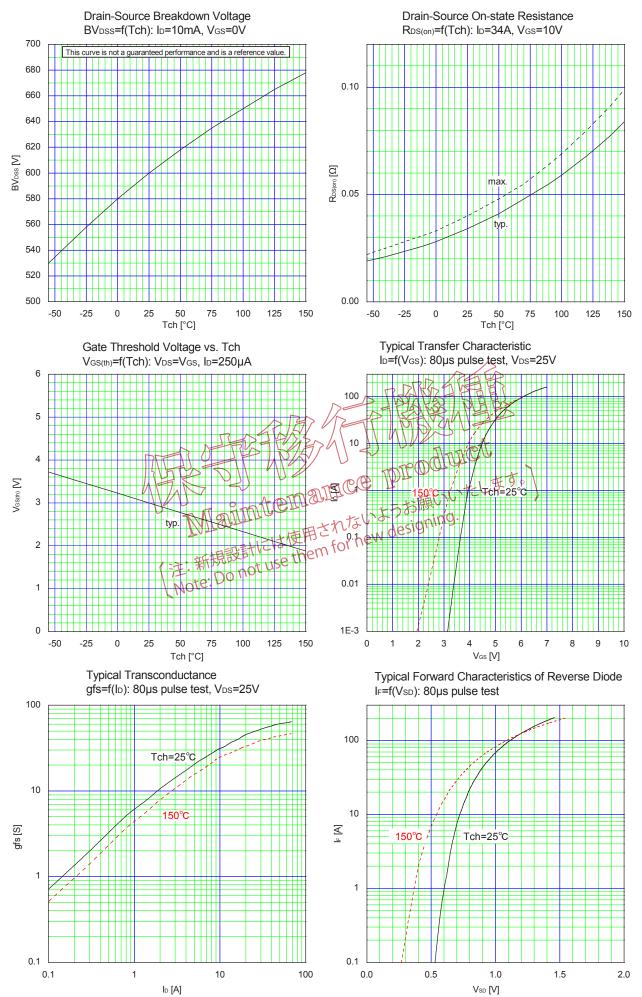
### Reverse Diode

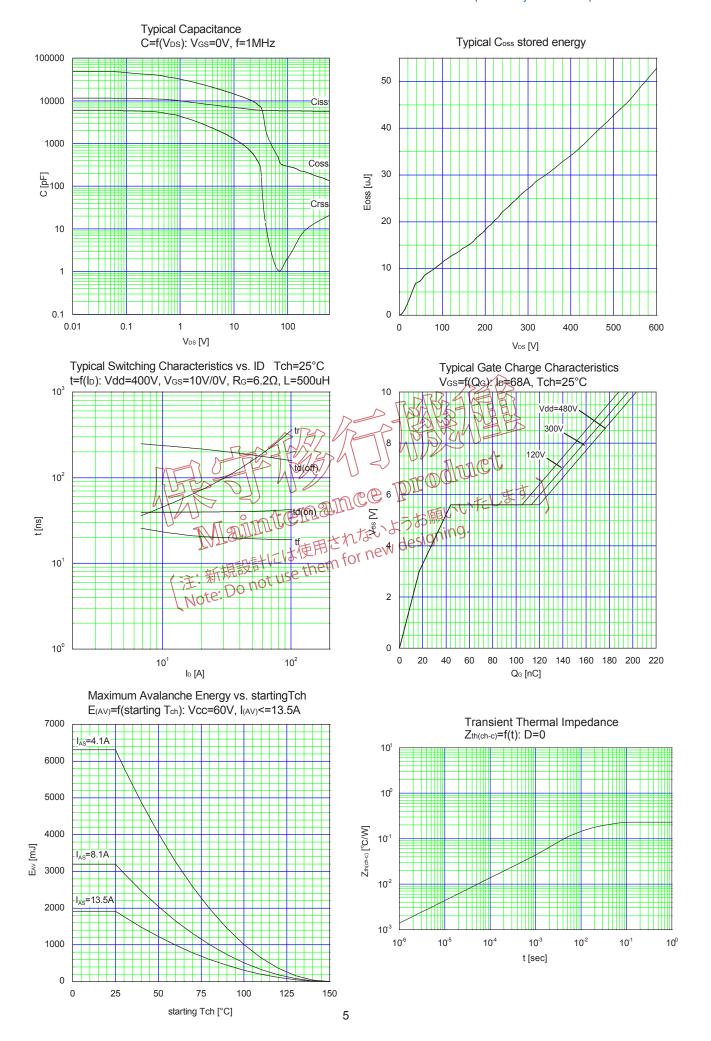
Parameter	Symbol	Conditions	min.	typ.	max.	Unit
Avalanche Capability	lav	L=19.3mH, T <sub>ch</sub> =25°C See Fig.1 and Fig.2	13.5	-	-	V
Diode Forward On-Voltage	V <sub>SD</sub>	I <sub>F</sub> =68A, V <sub>GS</sub> =0V T <sub>ch</sub> =25°C	-	1.0	1.35	V
Reverse Recovery Time	trr	I <sub>F</sub> =20A, V <sub>GS</sub> =0V V <sub>DD</sub> =300V -di/dt=50A/µs T <sub>ch</sub> =25°C See Fig.6 and Fig.7	-	600	-	ns
Reverse Recovery Charge	Qrr		-	8.7	-	μC
Peak Reverse Recovery Current	I <sub>rp</sub>		-	29	-	А

### ■ Thermal Resistance

Parameter	Symbol	min.	typ.	max.	Unit
Channel to Case	R <sub>th(ch-c)</sub>	-	-	0.23	°C/W
Channel to Ambient	R <sub>th(ch-a)</sub>	-	-	50	°C/W







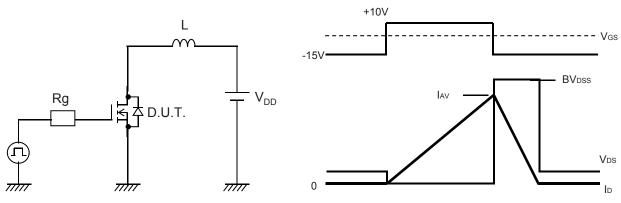


Fig.1 Avalanche Test circuit

Fig.2 Operating waveforms of Avalanche Test

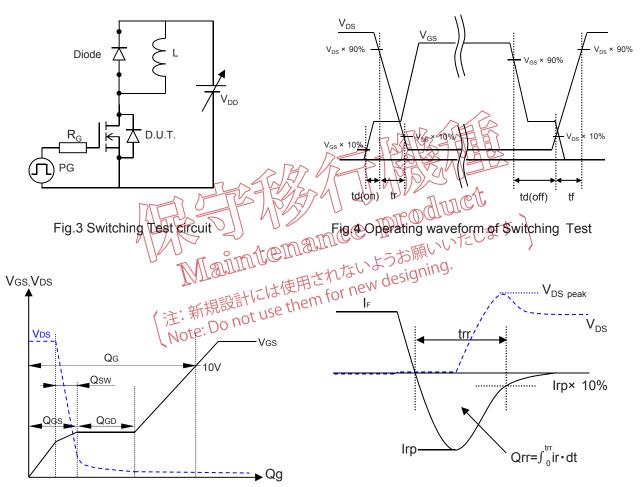
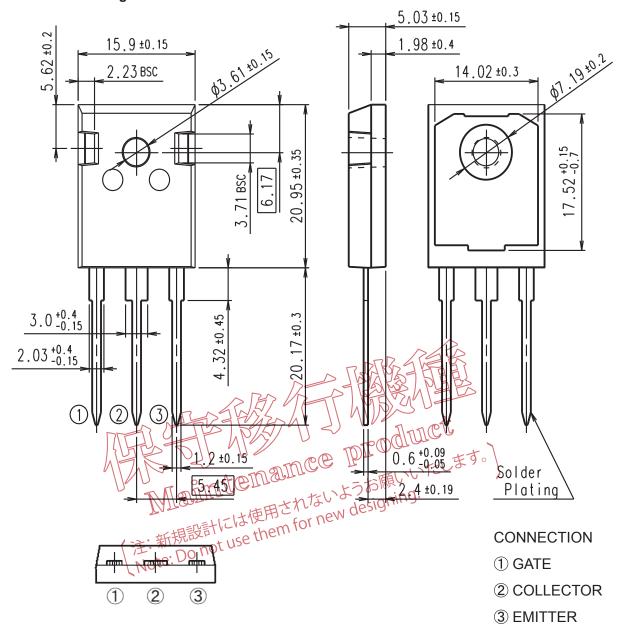


Fig.5 Operating waveform of Gate charge Test

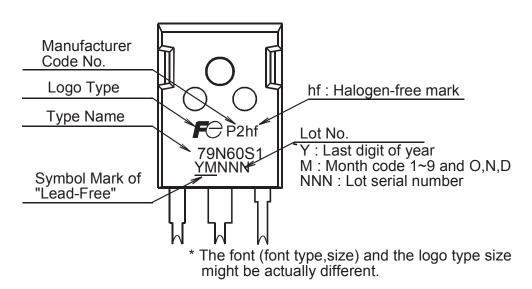
Fig.6 Operating waveform of Reverse recovery Test

### Outview: TO-247 Package



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